NSN 5961-00-097-9686

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-097-9686 **Inclosure Material:** Metal **Overall Length:** 1.125 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 1.031 inches and 1.063 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 1000.00 amperes peak forward surge current nanoamperes and 70.00 amperes forward current, total rms pascal **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 insulated wire lead w/terminal lug and 1 threaded stud **Specification Data:** 80131-release 3245 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0